

Self diffusion of Si and O in dacitic liquid at high pressures

DAVID TINKER AND CHARLES E. LESHER

Department of Geology, University of California, One Shields Avenue, Davis, California 95616, U.S.A.

ABSTRACT

Laboratory experiments have been conducted to determine simultaneously the self diffusivities of Si and O in synthetic dacite melt (NBO/T = 0.1) from 1 to 5.7 GPa and from 1355 to 1662 °C. Glasses enriched in ¹⁸O and ²⁸Si were synthesized and mated to their isotopically normal counterparts to form diffusion couples used in the piston cylinder device (1 and 2 GPa) and multi-anvil apparatus (4 to 5.7 GPa). Profiles of isotope abundances were measured by secondary ion mass spectrometry. Self-diffusion coefficients for Si (D_{Si}^*) are significantly lower than self-diffusion coefficients for O (D_O^*) at all run conditions; for example, $D_{Si}^* = 6.45 \pm 0.65 \times 10^{-14}$ m²/s and $D_O^* = 1.45 \pm 0.45 \times 10^{-14}$ m²/s at 1 GPa and 1355 °C. The temperature dependence is similar, but not identical, for Si and O self diffusion at all pressures, yielding activation energies of 293–380 kJ/mol at 1 GPa, 264–305 kJ/mol at 2 GPa, and 155–163 kJ/mol at 4 GPa. The pressure dependence is similar for Si and O at all temperatures, giving activation volumes for Si and O that are –14.5 to –17.1 cm³/mol at 1460 °C, –9.8 to –8.7 cm³/mol at 1561 °C, and –8.8 to –9.3 cm³/mol at 1662 °C. Self-diffusion coefficients for Si and O reach maximum values at roughly 5 GPa. The mode of Si and O self diffusion in dacitic liquids is constrained by the large activation volumes, $D_O^* \approx 2 D_{Si}^*$, and predictions using the Eyring equation, which suggest that Si and O diffuse as molecular species at 1460 °C. At 1561 and 1662 °C, less negative activation volumes and predictions of the Eyring equation are consistent with diffusion of Si and O by a combination of mechanisms, including the formation of a high-coordinated intermediate species.